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Team Nexperia



PESD3V3X1BCSF

Ultra low capacitance bidirectional ESD protection diode

17 August 2015

Product data sheet

1. General description

Ultra low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode a DSN0603-2 (SOD962) leadless ultra small Surface-Mounted Device (SMD) package.

2. Features and benefits

- Bidirectional ESD protection of one line
- Low diode capacitance $C_d = 1.1$ pF
- ESD protection up to ± 20 kV according to IEC 61000-4-2
- Ultra small SMD package

3. Applications

ESD and surge protection for:

- very sensitive interface lines
- generic interface lines

in portable electronics, communication, consumer and computing devices.

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C_d	diode capacitance	$f = 1$ MHz; $V_R = 0$ V; $T_{amb} = 25$ °C	-	-	1.1	pF
V_{RWM}	reverse standoff voltage	$T_{amb} = 25$ °C	-	-	3.3	V

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)	<p>Transparent top view</p> <p>DSN0603-2 (SOD962-2)</p>	<p>sym045</p>
2	K2	cathode (diode 2)		



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6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PESD3V3X1BCSF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2

7. Marking

Table 4. Marking codes

Type number	Marking code
PESD3V3X1BCSF	P

8. Limiting values

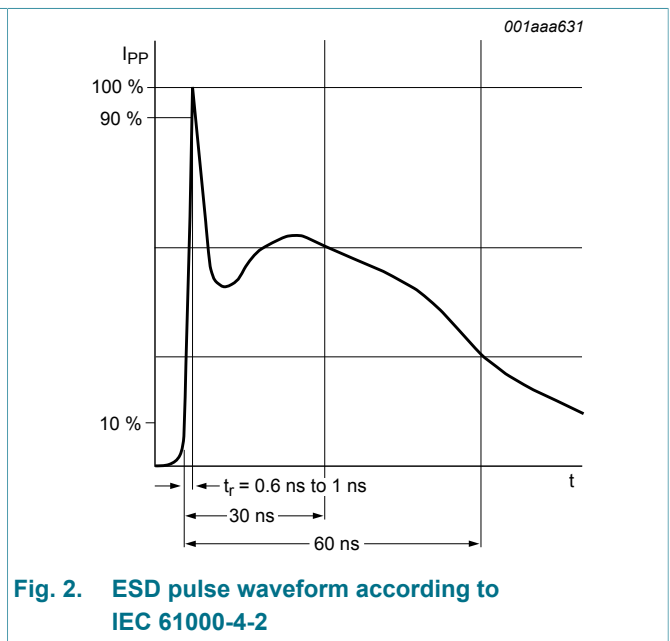
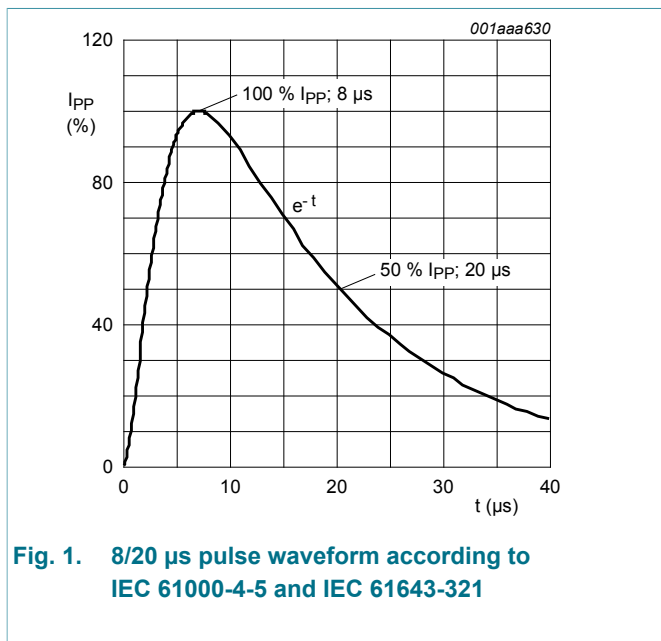
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
I_{PPM}	rated peak pulse current	t_p 8/20 μ s	[1]	-	8	A
T_j	junction temperature			-	150	$^{\circ}$ C
T_{amb}	ambient temperature			-40	125	$^{\circ}$ C
T_{stg}	storage temperature			-65	150	$^{\circ}$ C
ESD maximum ratings						
V_{ESD}	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	[2]	-	20	kV
		IEC 61000-4-2; air discharge	[2]	-	20	kV

[1] According to IEC 61000-4-5 and IEC 61643-321.

[2] Device stressed with ten non-repetitive ESD pulses.



9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{RWM}	reverse standoff voltage	$T_{amb} = 25\text{ }^{\circ}\text{C}$	-	-	3.3	V
I_{RM}	reverse leakage current	$V_{RWM} = 3.3\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$	-	1	100	nA
C_d	diode capacitance	$f = 1\text{ MHz}; V_R = 0\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}$	-	-	1.1	pF
V_{BR}	breakdown voltage	$I_R = 1\text{ mA}; T_{amb} = 25\text{ }^{\circ}\text{C}$	6	10	-	V
V_{CL}	clamping voltage	$I_{PP} = 8\text{ A}; T_{amb} = 25\text{ }^{\circ}\text{C}; t_p = 8/20\text{ }\mu\text{s}$	[1]	-	5.5	V
		$I_{PP} = 8\text{ A}; T_{amb} = 25\text{ }^{\circ}\text{C}; t_p = \text{TLP}$	[2]	-	4.6	V
		$I_{PP} = 16\text{ A}; T_{amb} = 25\text{ }^{\circ}\text{C}; t_p = \text{TLP}$	[2]	-	6.5	V
R_{dyn}	dynamic resistance	$I_R = 10\text{ A}; T_{amb} = 25\text{ }^{\circ}\text{C}$	[2]	0.25	-	Ω

[1] According to IEC 61000-4-5 and IEC 61643-321.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP) $t_p = 100\text{ ns}$; square pulse; ANSI / ESD STM5.5.1-2008.

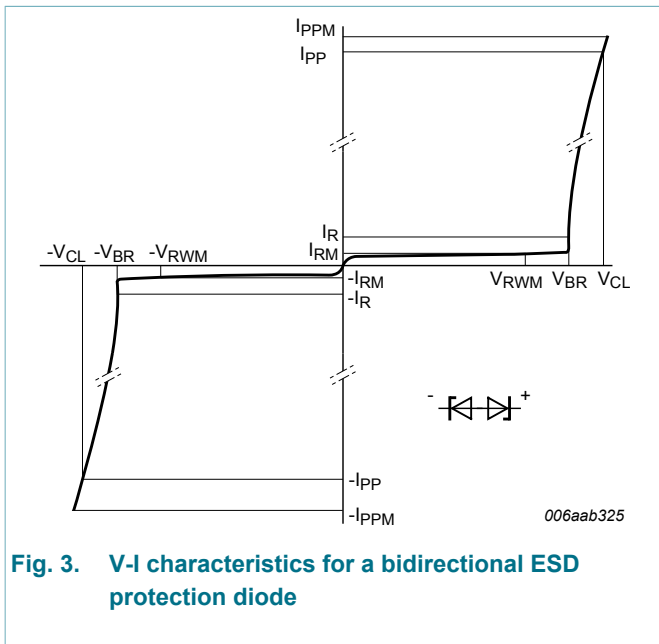


Fig. 3. V-I characteristics for a bidirectional ESD protection diode

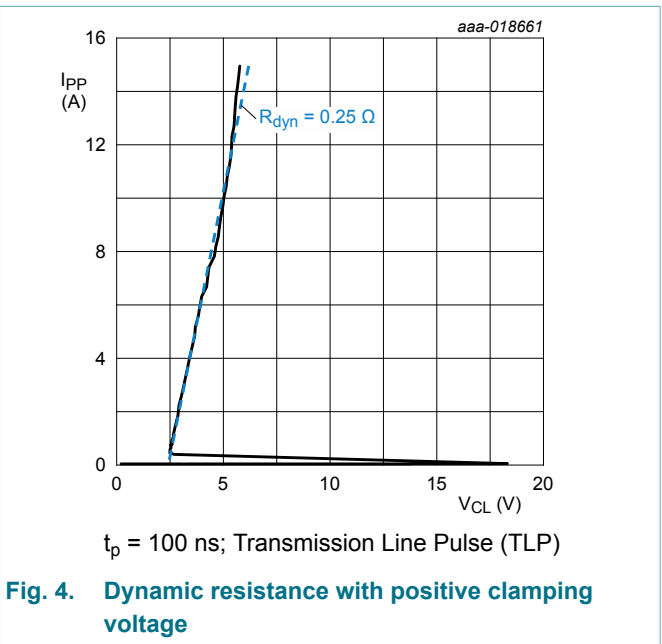
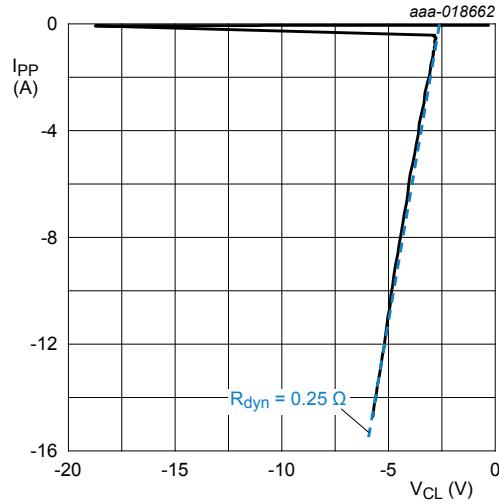
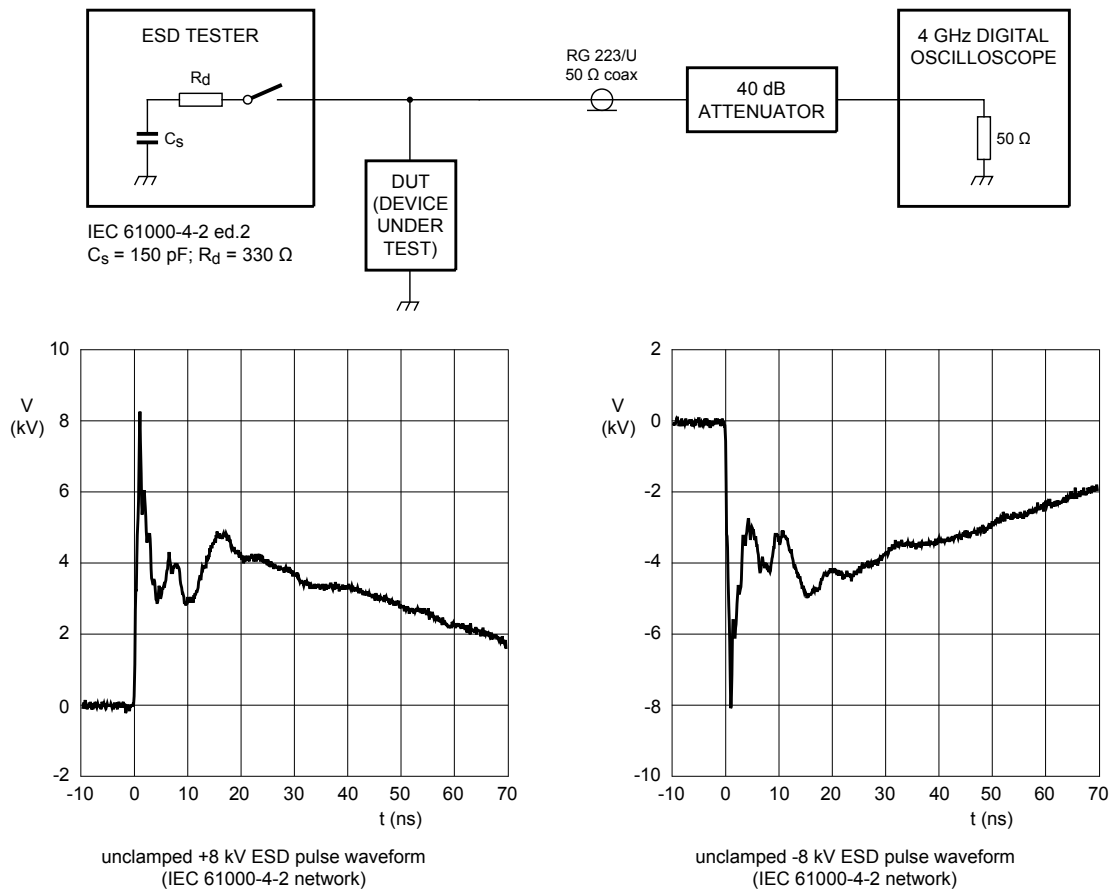


Fig. 4. Dynamic resistance with positive clamping voltage



$t_p = 100 \text{ ns}$; Transmission Line Pulse (TLP)

Fig. 5. Dynamic resistance with negative clamping voltage



aaa-003952

Fig. 6. ESD clamping test setup and waveforms

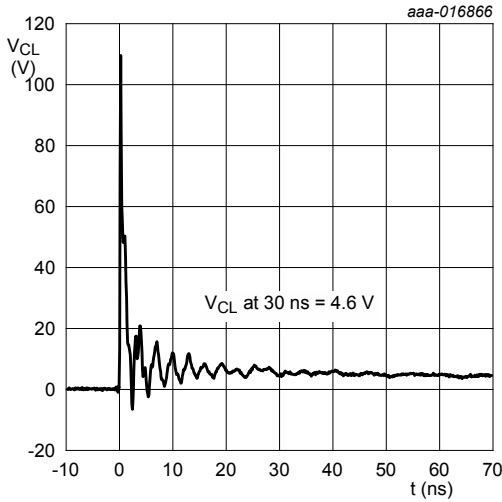


Fig. 7. Clamped +8 kV pulse waveform (IEC 61000-4-2 network)

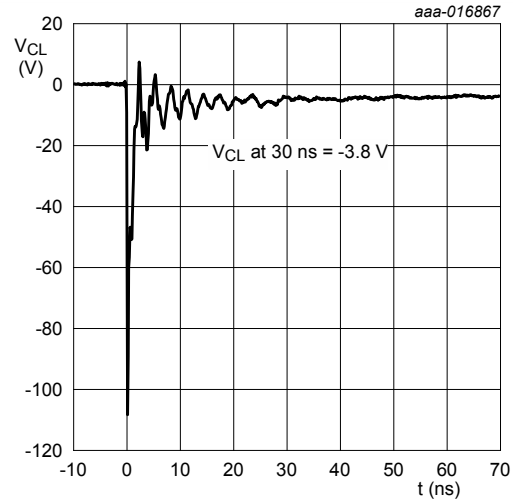


Fig. 8. Clamped -8 kV pulse waveform (IEC 61000-4-2 network)

10. Application information

The device is designed for the protection of one bidirectional data line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both positive and negative with respect to ground. The device is not designed to be used on lines connected to a DC supply.

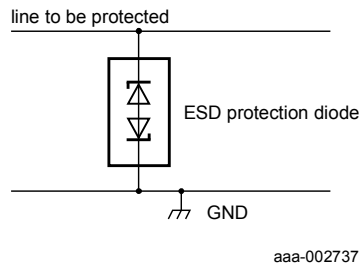


Fig. 9. Application diagram

Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

1. Place the device as close to the input terminal or connector as possible.
2. Minimize the path length between the device and the protected line.
3. Keep parallel signal paths to a minimum.
4. Avoid running protected conductors in parallel with unprotected conductors.
5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
6. Minimize the length of the transient return path to ground.
7. Avoid using shared transient return paths to a common ground point.
8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

11. Package outline

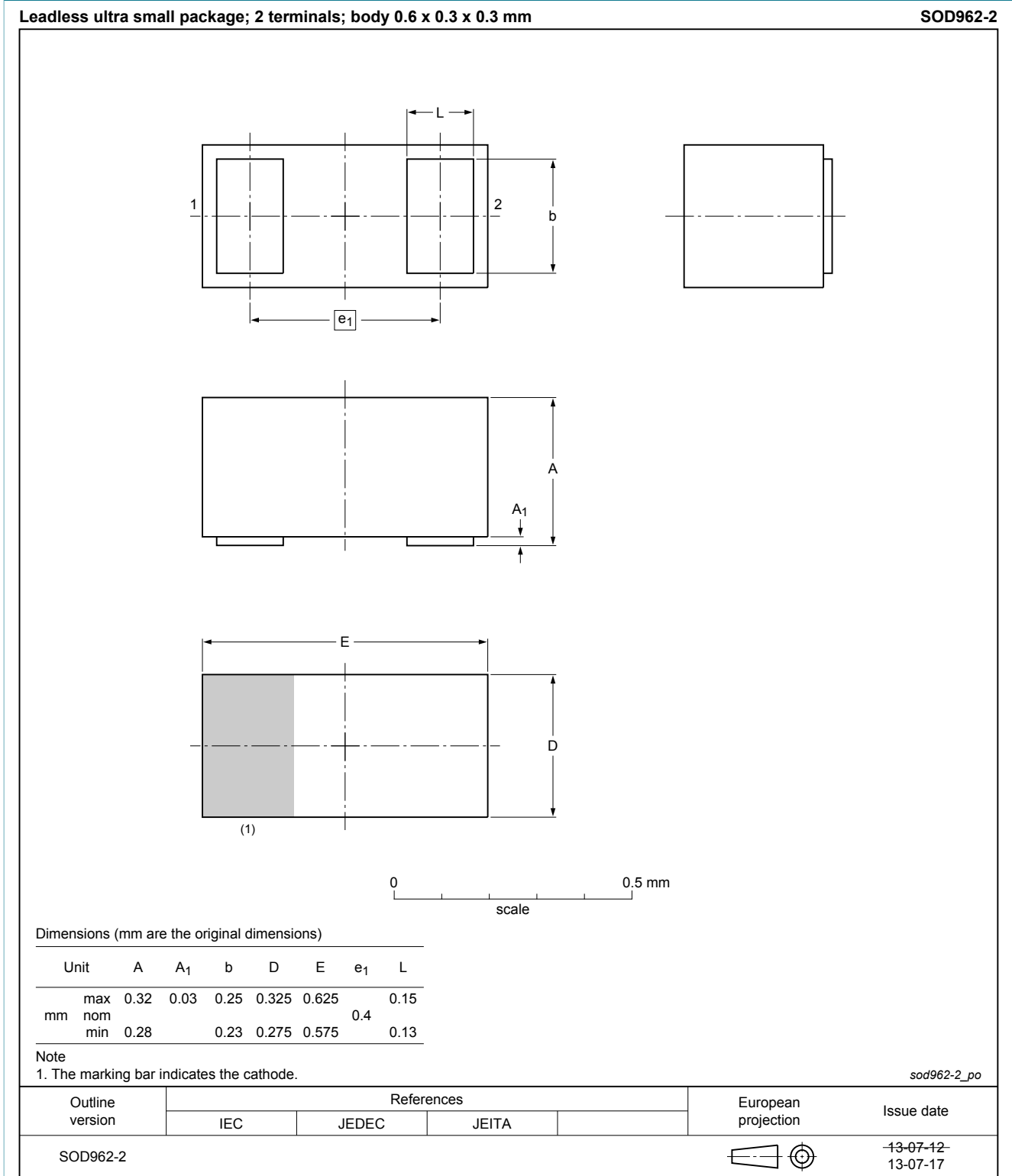
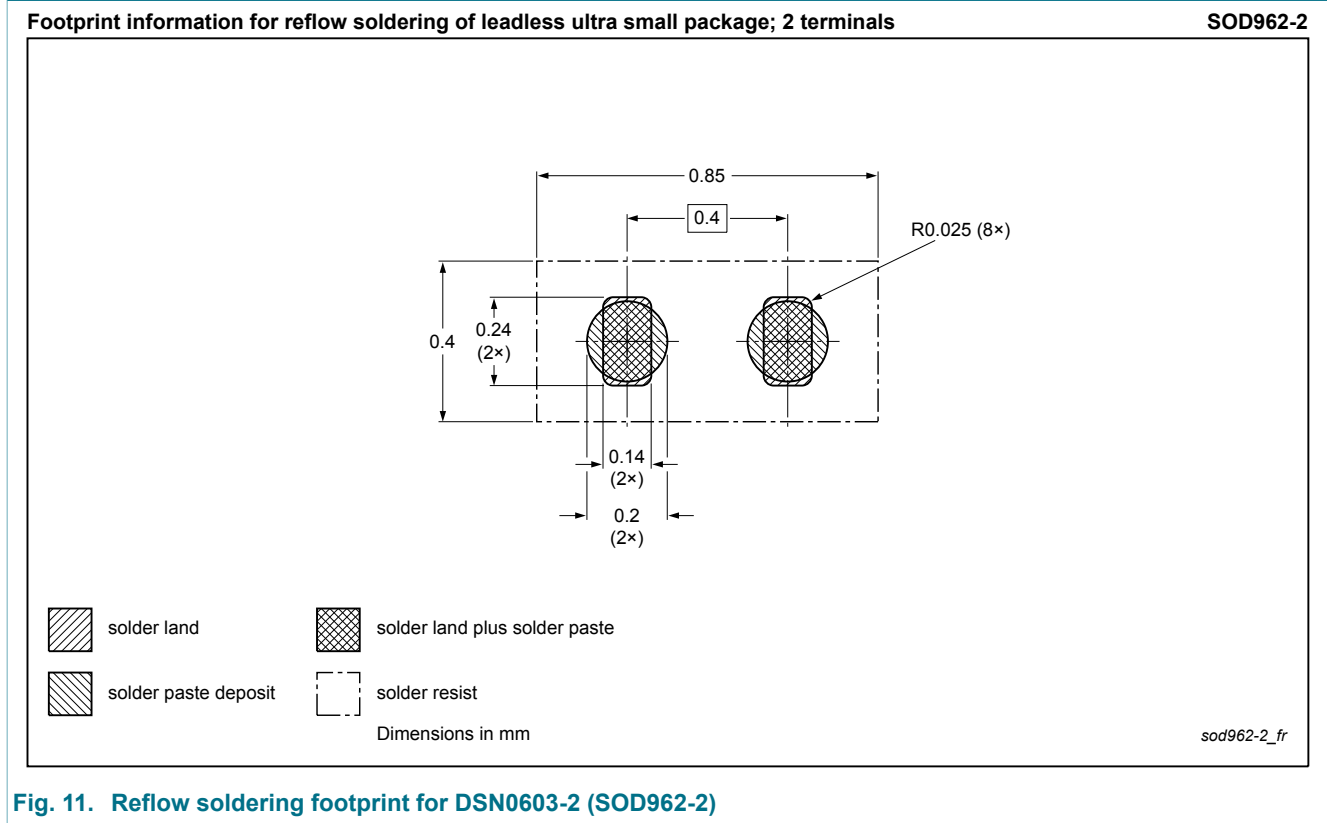


Fig. 10. Package outline DSN0603-2 (SOD962-2)

12. Soldering



13. Revision history

Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PESD3V3X1BCSF v.2	20150817	Product data sheet	-	PESD3V3X1BCSF v.1
Modification:	Changed condition for reverse leakage current.			
PESD3V3X1BCSF v.1	20150616	Product data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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